



### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

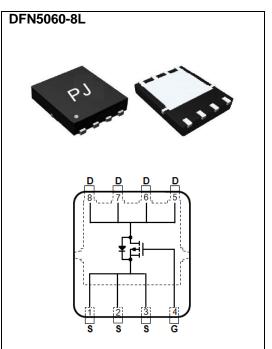
-30A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-8A<20mΩ
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-4.5V,I<sub>D</sub>@-6A<32mΩ
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage Gate-Source Voltage		V <sub>DS</sub>	-30	V	
			<u>+</u> 20		
Continuous Drain Current	T <sub>C</sub> =25°C	- I <sub>D</sub> -	-30	А	
	T <sub>C</sub> =100°C		-19		
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	-120		
Power Dissipation	T <sub>C</sub> =25°C	Po	27	107	
	T <sub>C</sub> =100°C		11	W	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-8.5	А	
	T <sub>A</sub> =70°C		-6.9		
Power Dissipation	T <sub>A</sub> =25°C	-	2.0	107	
Power Dissipation	T <sub>A</sub> =70°C	Po	1.3	W	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
(Note 4.5)	Junction to Case	$R_{ heta JC}$	4.6	°C/W	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	$BV_{DSS}$ $V_{GS}=0V,I_{D}=-250uA$		-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS(th)}$ $V_{DS}=V_{GS}, I_{D}=-250uA$		-1.5	-2.5		
Dunin Course On Otata Basista	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-8A	-	17	20	mΩ	
Drain-Source On-State Resistance		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-6A	-	26	32		
Zero Gate Voltage Drain Current	$I_{DSS}$	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_g$	45)/ 1 50	-	11	-	nC	
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	3.2	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-4.5V	-	3.9	-		
Input Capacitance	Ciss	\/ 45\/ \/ 0\/	-	1169	-		
Output Capacitance	Coss	$V_{DS}$ =-15V, $V_{GS}$ =0V,		180	-	pF	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	132	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/	-	5.9	-		
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-15V, $I_{D}$ =-1A,		33	-		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$	-	55	-	ns	
Turn-Off Fall Time	t <sub>f</sub>		-	34	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	-30	А	
Diode Forward Current	I <sub>S</sub>						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.73	-1	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$ =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

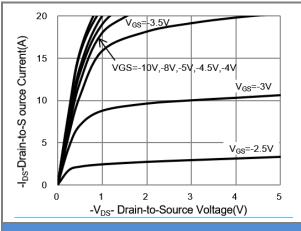
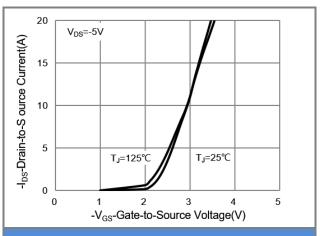


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

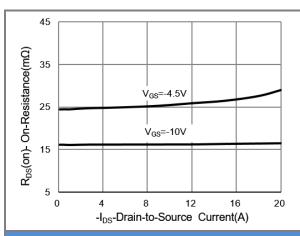


Fig.3 On-Resistance vs. Drain Current

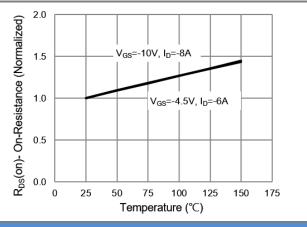


Fig.4 On-Resistance vs. Junction temperature

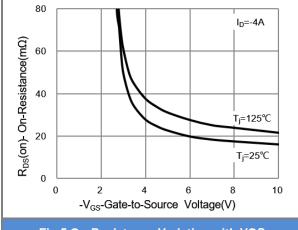
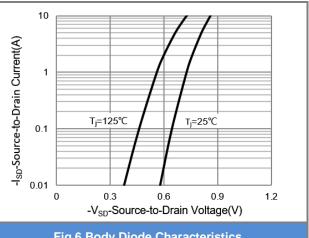


Fig.5 On-Resistance Variation with VGS.



**Fig.6 Body Diode Characteristics** 





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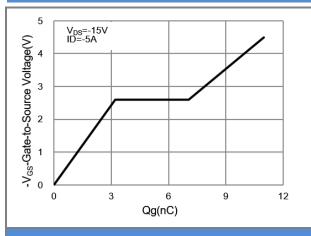


Fig.7 Gate-Charge Characteristics

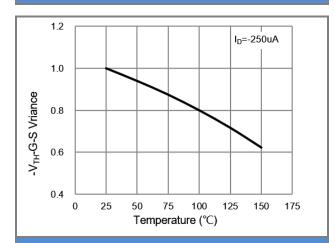


Fig.9 Threshold Voltage Variation with Temperature.

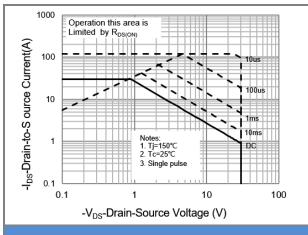


Fig.11 Maximum Safe Operating Area

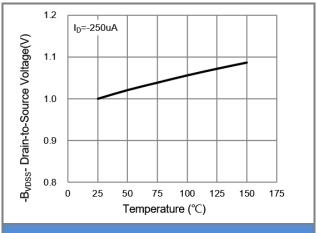


Fig.8 Breakdown Voltage Variation vs. Temperature

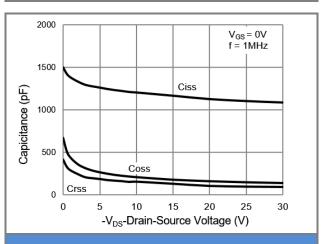


Fig.10 Capacitance vs. Drain-Source Voltage.





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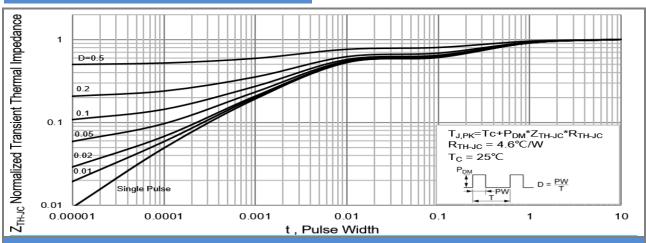


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

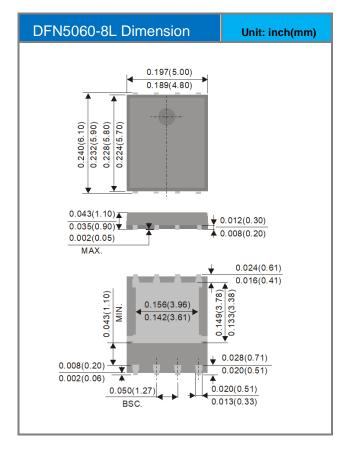


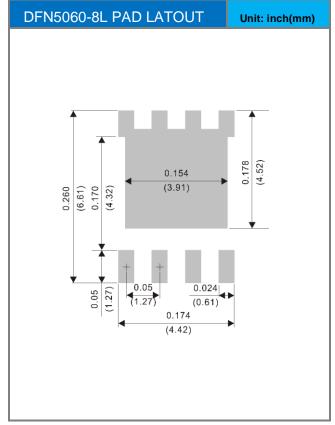


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ5419_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5419	Halogen free	

### **Packaging Information & Mounting Pad Layout**









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